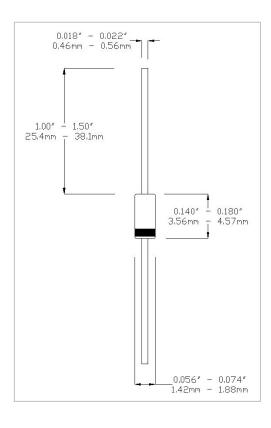
# 1N645-1

#### **FEATURES**

- 1N645-1 AVAILABLE IN JAN, JANTX, AND JANTXV PER MIL-PRF-19500/240
- SILICON RECTIFIER
- METALLURGICALLY BONDED
- HERMETICALLY SEALED
- DOUBLE PLUG CONSTRUCTION



#### MAXIMUM RATINGS AT 25 °C

Operating Temperature:  $-65^{\circ}\text{C}$  to  $+175^{\circ}\text{C}$ Storage Temperature:  $-65^{\circ}\text{C}$  to  $+175^{\circ}\text{C}$ 

Surge Current A, sine 8.3mS: 5.0A Total Power Dissipation: 500mW

Operating Current: 400 mA,  $T_A = +25 ^{\circ}\text{C}$ Operating Current: 150 mA,  $T_A = +150 ^{\circ}\text{C}$ Derating Factor:  $2 \text{mA} / ^{\circ}\text{C}$  above  $+25 ^{\circ}\text{C}$ Derating Factor:  $6 \text{mA} / ^{\circ}\text{C}$  above  $+150 ^{\circ}\text{C}$ 

D.C. Reverse Voltage (VRWM): 225V

### **DESIGN DATA**

Case: Hermetically sealed glass package per MIL-

PRF-19500/240 DO-35 outline **Lead Material:** Copper clad steel

Lead Finish: Tin/Lead

Thermal Resistance (R<sub>0JL</sub>): 250°C/W maximum

at L=.375"

Thermal Impedance (**Z<sub>0JX</sub>**): 35°C/W maximum

**Marking:** Blue body coat, Black digits. **Polarity:** Cathode end is banded.

### DC ELECTRICAL CHARACTERISTICS

$\mathbf{V_F}$				$I_R$			
Ambient (°C)	I <sub>F</sub> mA	Min V	Max V	Ambient (°C)	V <sub>R</sub> V (dc)	Min μA	Max μA
25	400	0.80	1.00	25	225	-	0.050
150	400	0.70	0.95	25	270(ac)	-	50
-55	400	-	1.20	150	225	-	25

#### AC ELECTRICAL CHARACTERISTICS AT 25°C

	Symbol	Min	Max
Capacitance @ $V_R = 4V$	pF	-	20



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